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# Complete 10 us CMOS 12-Bit ADC

## **General Description**

The MAX172 is a complete 12-Bit analog-to-digital converter (ADC) that combines high speed, low power consumption, and an on-chip voltage reference. The conversion time is 10 $\mu$ s. The buried zener reference provides low drift and low noise performance.

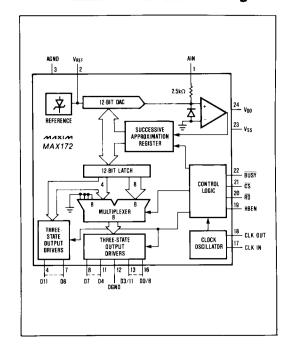
External component requirements are limited to only decoupling capacitors for the power supply and reference voltages. On-chip clock circuitry is also included which can either be driven from an external source, or in stand-alone applications, can be used with a crystal.

The MAX172 uses a standard microprocessor interface architecture. Three-state data outputs are controlled by Read (RD) and Chip Select (CS) inputs. Data access and bus release times of 90 and 75ns respectively ensure compatibility with most popular microprocessors without resorting to wait states.

## **Applications**

Digital Signal Processing (DSP) High Accuracy Process Control High Speed Data Acquisition Electro-Mechanical Systems

### Functional Diagram



# Features

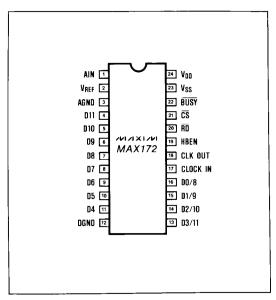
- ♦ 12-Bit Resolution and Linearity
- ♦ 10µs Conversion Time
- **♦ No Missing Codes**
- ♦ On-Chip Voltage Reference
- ♦ 90ns Access Time
- ◆ 215mW Max Power Consumption
- ♦ 24-Lead Narrow DIP Package
- ♦ Pin-for-Pin AD7572 Replacement

### **Ordering Information**

PART	TEMP RANGE	PIN- PACKAGE	ERROR (LSB)	PKG CODE
MAX172ACNG	0°C to +70°C	24 Plastic DIP	±0.5	N24-3
MAX172BCNG	0°C to +70°C	24 Plastic DIP	±1	N24-3
MAX172ACWG	0°C to +70°C	24 Wide SO	±0.5	W24-1
MAX172BCWG	0°C to +70°C	24 Wide SO	±1	W24-1
MAX172CC/D	0°C to +70°C	Dice*	±1	_
MAX172AENG	-40°C to +85°C	24 Plastic DIP	±0.5	N24-3
MAX172BENG	-40°C to +85°C	24 Plastic DIP	±1	N24-3
MAX172AMRG	-55°C to +125°C	24 CERDIP	±0.5	R24-4
MAX172BMRG	-55°C to +125°C	24 CERDIP	±1	R24-4

\* Consult factory for dice specifications

## Pin Configuration



Maxim Integrated Products

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# ABSOLUTE MAXIMUM RATINGS

$\begin{array}{cccccccccccccccccccccccccccccccccccc$	Operating Temperature Ranges         MAX172XC         0°C to +70°           MAX172XE         -40°C to +85°
AIN to AGND15V to +15V Digital Input Voltage to DGND0.3V, V <sub>DD</sub> + 0.3V (Pins 17, 19-21)	MAX172XM
Digital Output Voltage to DGND0.3V, V <sub>DD</sub> + 0.3V (pins 4-11, 13-16, 18, 22)	Derates Above +75°C by

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum ratings conditions for extended periods may affect device reliability.

**ELECTRICAL CHARACTERISTICS** ( $V_{DD}$  = +5V  $\pm$  5%,  $V_{SS}$  = -12V or -15V  $\pm$  5%; Slow Memory Mode;  $T_A$  =  $T_{MIN}$  to  $T_{MAX}$  unless otherwise noted,  $f_{CLK}$  = 1.25MHz.)

PARAMETER	SYMBOL	CONDITIONS			TYP	MAX	UNITS	
ACCURACY					-			
Resolution				12			Bits	
		MAX172A	T <sub>A</sub> = 25°C			+ 1/2		
Integral NonLinearity	INL	MAX172AC/AE MAX172AM MAX172B	MAX172AC/AE MAX172AM				LSB	
Differential NonLinearity	DNL	Guaranteed Monot	onic Over Temp.			+1	LSB	
		MAX172B	T. = 25°C				1.05	
Offset Error (Note 1)	:	MAX172A	$T_A = 25^{\circ}C$ $T_A = T_{MIN} \text{ to } T_{MAX}$			±3 ±4	⊢ LSB	
		MAX172B	T <sub>A</sub> = 25°C			+ 15	LSB	
Full Scale Error (Note 2)		MAX172A	T <sub>A</sub> = 25°C			+ 10	LSB	
Full Scale Tempco (Notes 3, 4)						+ 45	ppm/°C	
ANALOG INPUT								
Input Voltage Range				0		5	V	
Input Current		AIN = 0V to +5V				3.5	rnA	
INTERNAL REFERENCE								
V <sub>REF</sub> Output Voltage		T <sub>A</sub> = 25°C		-5.2	-5.25	-5.3	V	
V <sub>REF</sub> Output Tempco (Note 5)					40		ppm/°	
Output Current Sink Capability		(Note 6)				500	μΑ	
LOGIC INPUTS								
Input Low Voltage	V <sub>IL</sub>	CS, RD, HBEN, C	LKIN			0.8	V	
Input High Voltage	V <sub>IH</sub>	CS, RD, HBEN, C	LKIN	2.4			V	
Input Capacitance (Note 7)	C <sub>IN</sub>	CS, RD, HBEN, C	LKIN			10	pF	
Input Current	I <sub>IN</sub>	CS, RD, HBEN CLKIN	VIN = 0 to V <sub>DD</sub>			+ 10 + 20	μΑ	
LOGIC OUTPUTS								
Output Low Voltage	V <sub>OL</sub>	D11-D0/8, BUSY, (	CLKOUT I <sub>SINK</sub> = 1.6mA			0.4	V	
Output High Voltage	V <sub>OH</sub>	D11-D0/8, BUSY, CLKOUT I <sub>SOURCE</sub> = 200µA		4			V	
Floating State Leakage Current	I <sub>LKG</sub>	D11-D0/8, V <sub>OUT</sub> =			+ 10	μΑ		
Floating State Output Capacitance (Note 7)	C <sub>OUT</sub>					15	pF	

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# Complete 10 µs CMOS 12-Bit ADC

**ELECTRICAL CHARACTERISTICS (Continued)**  $(V_{DD} = +5V + 5W, V_{SS} = -12V \text{ or } -15V \pm 5W$ ; Slow Memory Mode;  $T_A = T_{MIN}$  to  $T_{MAX}$  unless otherwise noted,  $f_{CLK} = 1.25MHz$ .)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
CONVERSION TIME						
MAX172	t <sub>CONV</sub>	Synchronous (12.5 clock cycles) Asynchronous (12 to 13 clock cycles)	9.6		10 10.4	μS
POWER SUPPLY REJECT	ION					
V <sub>DD</sub> Only		FS Change, $V_{SS} = -15V$ , $V_{DD} = 4.75V$ to 5.25V		±1/2		LSB
V <sub>SS</sub> Only		FS Change, V <sub>DD</sub> = 5V, V <sub>SS</sub> = -5% to +5% ± 1/8				
POWER REQUIREMENTS						
V <sub>DD</sub>		±5% for Specified Performance		5		VV
V <sub>SS</sub> (Note 8)		±5% for Specified Performance		-12 or -1	5	
I <sub>DD</sub>		CS = RD = V <sub>DD</sub> , AIN = 5V		5	7	mA
Iss		$\overline{\text{CS}} = \overline{\text{RD}} = V_{\text{DD}}, \text{ AIN} = 5V$ 8 12				mA
Power Dissipation		$V_{DD} = +5V, V_{SS} = -15V$ 145 215				

Note 1: Typical change over temp is +1 LSB. Note 2:  $V_{DD} = +5V$ ,  $V_{SS} = -15V$ , FS = +5.000V, Ideal last code transition = FS - 3/2LSB. Note 3: Full Scale TC =  $\Delta$ FS/ $\Delta$ T, where  $\Delta$ FS is full scale change from  $T_A = 25^{\circ}$ C to  $T_{MIN}$  or  $T_{MAX}$ .

Note 4: Includes internal reference drift.

Note 5: V<sub>REF</sub> TC = ΔV<sub>REF</sub>/ΔT, where ΔV<sub>REF</sub> is reference voltage change from T<sub>A</sub> = 25°C to T<sub>MIN</sub> or T<sub>MAX</sub>.

Note 6: Output current should not change during conversion.

Note 7: Guaranteed by design, not subject to test.

Note 8: Functional operation at V<sub>SS</sub> = -12V + 5% is guaranteed by testing offset error and full scale error.

#### TIMING CHARACTERISTICS (Note 9)

(V<sub>DD</sub> = +5V, V<sub>SS</sub> = -12V or -15V;  $T_A = T_{MIN}$  to  $T_{MAX}$  unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS -	T	T <sub>A</sub> = 25°C		MAX172C/E		MAX172M		UNITS
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
CS to RD Setup Time	t <sub>1</sub>		0			0		0		ns
RD to BUSY Delay	t <sub>2</sub>	C <sub>L</sub> = 50pF		90	190		230		270	ns
Data Access Time (Note 10)	t <sub>3</sub>	C <sub>L</sub> = 20pF C <sub>L</sub> = 100pF		60 70	90 125		110 150	_	120 170	ns
RD Pulse Width	t <sub>4</sub>		t <sub>3</sub>			$t_3$		t <sub>3</sub>		
CS to RD Hold Time	t <sub>5</sub>		0			0		0		ns
Data Setup Time After BUSY Note (10)	t <sub>6</sub>				70	_	90		100	ns
Bus Relinquish Time (Note 11)	t <sub>7</sub>		20		75	20	85	20	90	ns
HBEN to RD Setup Time	t <sub>8</sub>		0			0		0		ns
HBEN to RD Hold Time	t <sub>9</sub>		0			0		0		ns
Delay Between Read Operations	t <sub>10</sub>		200			200		200		ns

Timing specifications are sample tested at 25°C to ensure compliance. All input control signals are specified with

 $t_r = t_1 = 5$ ns (10% to 90% of +5V) and timed from a voltage level of +1.6V.  $t_3$  and  $t_6$  are measured with the load circuits of Figure 1 and defined as the time required for an output to cross Note 10:

Note 11: t<sub>7</sub> is defined as the time required for the data lines to change 0.5V when loaded with the circuits of Figure 2.

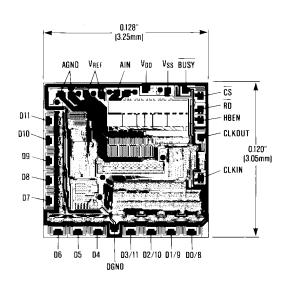
# For additional information on using the MAX172 please refer to MAX162 data sheet.

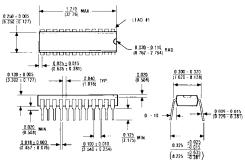
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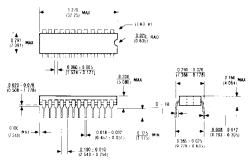
## Chip Topography

# Package Information

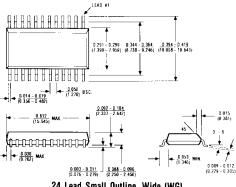




24 Lead Plastic Narrow DIP (NG)  $\theta_{JA} = 120^{\circ}C/W$   $\theta_{JC} = 60^{\circ}C/W$ 



24 Lead Narrow CERDIP (RG)  $\theta_{JA}=80^{\circ}\text{C/W}$  $\theta_{JC} = 40^{\circ}C/W$ 



24 Lead Small Outline, Wide (WG)  $\theta_{JA} = 85^{\circ}\text{C/W}$  $\theta_{JC}^{NA} = 45^{\circ} \text{ C/W}$ 

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